

ZXT11N20DF

20V NPN LOW SATURATION TRANSISTOR IN SOT23

Features

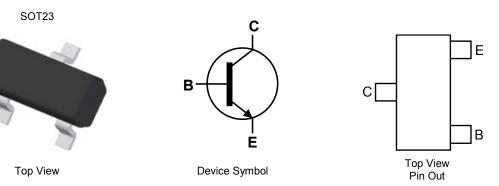
- BV_{CEO} = 20V
- Low Saturation Voltage V_{CE(sat)} < 12mV @ 100mA
- I_C = 2.5A Continuous Current
- R_{sat} = 40mΩ for a Low Equivalent On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: SOT23
- Case Material: Molded plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.008 grams (Approximate)

Application

- DC DC converters
- Power management functions
- Power switches
- Motor control



Ordering Information (Note 4)

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Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXT11N20DFTA	Standard	2N0	7	8	3000

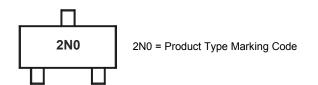
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	40	V
Collector-Emitter Voltage	V _{CEO}	20	V
Emitter-Base Voltage	V _{EBO}	7.5	V
Continuous Collector Current	Ι _C	2.5	A
Peak Pulse Collector Current (single pulse)	ICM	5	A
Base Current	IB	500	mA

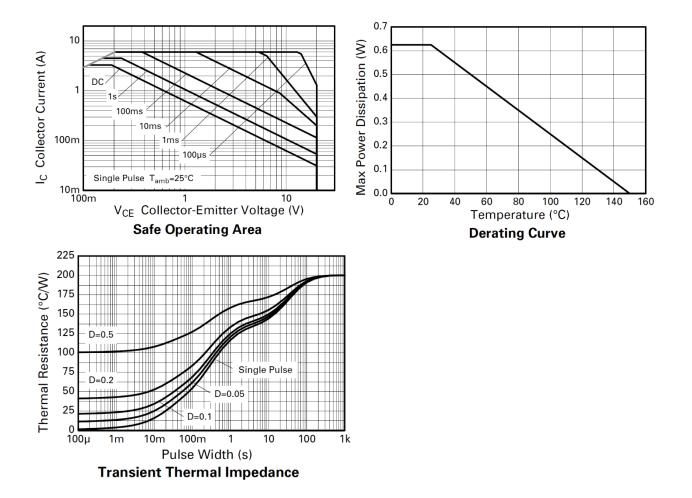
Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) Linear Derating Factor	PD	625 5	W mW/°C
Power Dissipation (Note 6) Linear Derating Factor	PD	806 6.4	W mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	200	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	155	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

 For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; device measured when operating in steady state condition.
Same as note (5), except the device is measured at t<5 seconds. Notes:



Thermal Characteristics and Derating Information





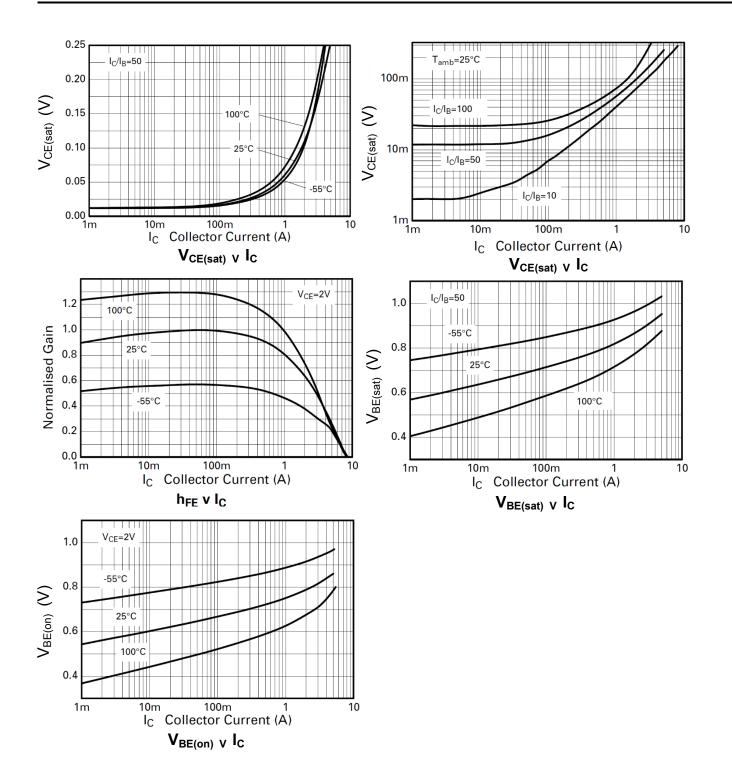
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	40			V	$I_{\rm C} = 100 \mu \text{A}$
Collector- Emitter Breakdown Voltage (Note 7)	BVCBO	20	_		V	$l_c = 100\mu$ A
Emitter-Base Breakdown Voltage	BVCEO BVEBO	7.5	_		V	$I_E = 100\mu A$
Collector Cut-Off Current	ICBO	1.5		100	nA	V _{CB} = 32V
Collector Emitter Cut-Off Current	ICBO			100	nA	V _{CES} = 32V
Emitter Cut-Off Current	I _{EBO}	_	_	100	nA	V _{ES} = 6V
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	_	7 65 40 90	12 100 60 130	mV	$I_{C} = 100mA$, $I_{B} = 10mA$ $I_{C} = 1A$, $I_{B} = 10mA$ $I_{C} = 1A$, $I_{B} = 10mA$ $I_{C} = 1A$, $I_{B} = 100mA$ $I_{C} = 2.5A$, $I_{B} = 250mA$
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	—	0.9	1.0	V	I _C = 2.5A, I _B = 250mA
Base-Emitter Turn-On Voltage (Note 7)	V _{BE(on)}	—	0.85	1.0	V	I _C = 2.5A, V _{CE} = 2V
DC Current Gain (Note 7)	hfe	200 300 250 150 100	_	 900 	_	$\begin{split} I_{C} &= 10 \text{mA}, \ V_{CE} &= 2 \text{V} \\ I_{C} &= 100 \text{mA}, \ V_{CE} &= 2 \text{V} \\ I_{C} &= 1\text{A}, \ V_{CE} &= 2 \text{V} \\ I_{C} &= 3\text{A}, \ V_{CE} &= 2 \text{V} \\ I_{C} &= 5\text{A}, \ V_{CE} &= 2 \text{V} \end{split}$
Transitional frequency	f _T	_	160	_	MHz	I _C = 50mA, V _{CE} = 10V f = 50MHz
Output Capacitance	C _{obo}	_	20	_	pF	V _{CB} = 10V, f = 1MHz
Switching Time	t _{on}		122	_	ns	I _C = 2A, V _{CC} = 10V,
	t _{off}		295		110	$I_{B1} = -I_{B2} = 20mA$

Note: 7. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



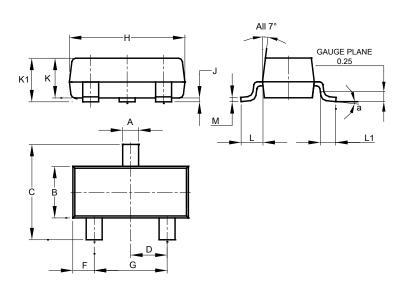
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

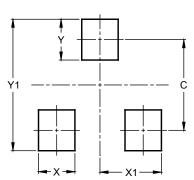
Please see http://www.diodes.com/package-outlines.html for the latest version.



	50	T23			
			Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
с	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
κ	0.890	1.00	0.975		
K1	0.903	1.10	1.025		
L	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	0°	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

SOT23

SOT23



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